## NSN 5961-01-307-9039

Diode Semiconductor Device - Page 1 of 1



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End Application:
F15 acft
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 breakdown voltage, dc
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius case
Special Features:
Trw microwave silicon recovery diodes are designed for use in high performance frequency multiplier circuits with output frequencies from
uhf to 18.0 ghz
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0